


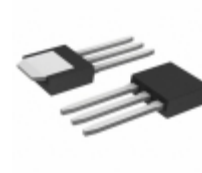
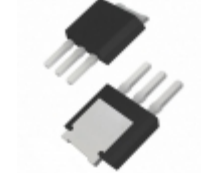



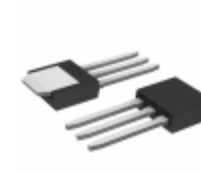
	<h2 style="color: red;">NTD70N03RT4G</h2>	
	Hersteller-Teilenummer:	NTD70N03RT4G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 25V 10A DPAK
Datenblätter:	 NTD70N03RT4G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 35426 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	NTD70N03RT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 10A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35426 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.36W (Ta), 62.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	8 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13.2nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1333pF @ 20V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 NTD70N03TR4 O NTD70N03TR4 O	 NTD70N03RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 10A DPAK	 NTD70N03R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 10A IPAK	 NTD78N03-035 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A IPAK
 NTD70N03R-1 ON NTD70N03R-1 ON	 NTD70N03RG AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 10A DPAK	 NTD70N03R-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 10A IPAK	 NTD78N03-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A IPAK

heiße Teile

Mehr

 NTD6416ANG	 NTD6416ANL	 NTD6416ANL-1G	 D NTD6416ANLT4G	 NTD6416ANT4G
 NTD65N03G	 NTD65N03R-001	 D NTD65N03R-035	 NTD65N03R-1G	 NTD65N03R-35G
 NTD65N03RG	 NTD65N03RT4G	 NTD6600G	 NTD6600N	 NTD6600N-001
 D NTD6600N-1G	 NTD6600NT4	 NTD6600NT4G	 NTD70N03	 NTD70N03R
 NTD70N03R-001	 NTD70N03R-1	 NTD70N03R-1G	 NTD70N03RG	 NTD70N03RT4
 NTD70N03TR4	 NTD78N03	 D NTD78N03-001	 NTD78N03-035	 NTD78N03-1
 NTD78N03-1G	 D NTD78N03-35G	 NTD78N03R-001	 NTD78N03R-1G	 NTD78N03RT4G
 NTD78N03T4	 NTD78N03T4G	 NTD80N02	 NTD80N02-001	 NTD80N02-1
 NTD80N02-1G	 NTD80N02G	 NTD80N02T4	 D NTD80N02T4G	 NTD85N02-1G
 NTD85N02R	 NTD85N02R-001	 NTD85N02R-1	 NTD85N02R-1G	 NTD85N02R14

Contact us: Info@Y-IC.com

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